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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/086,942	03/01/2002	Cem Basceri	MI22-1951	3748
21567 75	590 02/28/2003			
WELLS ST. JOHN ROBERTS GREGORY & MATKIN P.S.			EXAMINER	
601 W. FIRST SUITE 1300	AVENUE	HUYNH, YENNHU B		
SPOKANE, WA 99201-3828				
, ,			ART UNIT	PAPER NUMBER
			2813	10
			DATE MAILED: 02/28/2003	10

Please find below and/or attached an Office communication concerning this application or proceeding.

		LAWRENCE AL		('m
	•	Application No.	Applicant(s)	`
Office Action Summary		10/086,942	BASCERI, CEM	
	Office Action Summary	Examiner	Art Unit	
	The MAN INC DATE of the control of	Yennhu B Huynh	2813	
Period fo	Th MAILING DATE of this communication apported in Reply	pears on the cover she it with the	correspondenc add	ress
THE I - External after - If the - If NC - Failur - Any r	ORTENED STATUTORY PERIOD FOR REPL'MAILING DATE OF THIS COMMUNICATION.  nsions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication.  period for reply specified above is less than thirty (30) days, a reply of period for reply is specified above, the maximum statutory period of the to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be ti y within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS from , cause the application to become ABANDON	mely filed  ys will be considered timely.  the mailing date of this com  ED (35 U.S.C. & 133).	nmunication.
1)⊠	Responsive to communication(s) filed on 03 F	ebruary 2003 .		
2a)⊠	This action is <b>FINAL</b> . 2b) Th	is action is non-final.		
3) Dispositi	Since this application is in condition for allowed closed in accordance with the practice under ion of Claims	ance except for formal matters, p Ex parte Quayle, 1935 C.D. 11, 4	rosecution as to the 453 O.G. 213.	merits is
4)🖂	Claim(s) <u>43-47,49-51,53,54 and 58-65</u> is/are p	pending in the application.		
	4a) Of the above claim(s) is/are withdraw	wn from consideration.		
5)	Claim(s) is/are allowed.			
6)⊠	Claim(s) <u>43-47,49-51,53,54 and 58-65</u> is/are re	ejected.		
7)	Claim(s) is/are objected to.			
1	Claim(s) are subject to restriction and/or	r election requirement.		
	on Papers			
i	The specification is objected to by the Examine			
10)	The drawing(s) filed on is/are: a)☐ accep			
	Applicant may not request that any objection to the			
<u> </u>		_is: a) ☐ approved b) ☐ disappro	oved by the Examiner.	· · - · -
12)	If approved, corrected drawings are required in rep	•		
	The oath or declaration is objected to by the Ex	aminer.		
	inder 35 U.S.C. §§ 119 and 120			
	Acknowledgment is made of a claim for foreign	i priority under 35 U.S.C. § 119(a	a)-(d) or (f).	
a)[	All b) Some * c) None of:			
	1. Certified copies of the priority documents			
	2. Certified copies of the priority documents			
* S	3. Copies of the certified copies of the prior application from the International But see the attached detailed Office action for a list	reau (PCT Rule 17.2(a)).		age
	cknowledgment is made of a claim for domestic	·		pplication).
a)	)  The translation of the foreign language pro Acknowledgment is made of a claim for domesti	visional application has been rec	ceived.	,
Attachment	•	5 p. 10. 10 0. 0. 0. 0. 0. 0. 0. 0. 0. 0. 0. 0. 0.	. union or the ti	
1) Notice	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) <u>11</u>	5) Notice of Informal	y (PTO-413) Paper No(s) Patent Application (PTO-	
U.S. Patent and Tr. PTO-326 (Rev		tion Summary	Part of Pa	per No. 12

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### **DETAILED ACTION**

This Office Action is in response to the RCE filled on 2/3/03

Claims 48,52 & 55-57 are cancelled by Amendment filled on 2/3/03.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

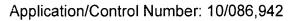
Claim 43 is rejected under 35 U.S.C. 102(b) as anticipated Summerfelt et al. (U.S. 6,362,068B1)

materials of BST, which include a first capacitor electrode 30; a first perovskite type dielectric material layer 32; wherein the second layer having a different amount of cystallinity than the first layer (col. 3 & 4, lines 55-4); a second capacitor electrode 46 over the perovskite type dielectric material.

# Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:





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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 43-47, 49,51,53,54 & 58-65 are rejected under 35 U.S.C. 103(a) as being unpatentable over Summerfelt et al. (U.S. 6,362,068B1) in view of Sone (U.S. 6,323,057B1).

Summerfelt et al. at figs. 1-5 in related art col.1-8 disclose a capacitor dielectric materials of BST, which include a first capacitor electrode 30; a first perovskite type dielectric material layer 32; wherein the second layer having a different amount of crystallinity than the first layer (col. 3 & 4, lines 55-4); a second capacitor electrode 46 over the perovskite type dielectric material. Summerfelt also disclose a BST thickness of 100nm (10 angstrom) and a ST of 53nm (col.3, lines 30-32) or a variety thickness of BST or ST (table 1, table 2, col.2, col. 6); the first layer has less crystallinity than the second layer (col.6, lines 43-48); a third perovskite type dielectric material layer 36; wherein the perovskite type material comprises Ba, Str, Titanium, Titanate and oxide; wherein the perovskite type material has different or same chemical composition in the second layer than in the first layer (col.3, lines 17-17-43); wherein the perovskite type material comprises one or more BST, BT, PZT and lanthanum doped PZT (col.1, lines 44-61); wherein the capacitor electrode layers comprises a metal Platinum.

However, Summerfelt et al. do not disclose the first layer is substantially amorphous and the second layer is substantially crystalline.

Sone in related art col. 1-12 and figs. 1-12 disclose a thin film capacitor, which include forming a perovskite amorphous film on the bottom electrode, and a crystallized

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film is formed at the second step due to heat treatment; wherein the perovskite material comprises Sr, Ba, Pb, Ti, Zr, and La (col. 5, lines 31-37).

It would have been obvious to one having skill in the art at the time the invention was made to modify the invention of Summerfelt et al. by incorporating an amorphous perovskite material film formed on a Platinum capacitor electrode, to provide a good surface evenness for the bottom electrode, and make a sufficiently high relative dielectric constant to reduce leakage current.

With respect to claim 44 the time, concentration, cycles and thickness are considered to involve routine optimization while has been held to be within the level of ordinary skill in the art, As noted In re Aller 105 USPQ233, 255 (CCPA 1955)., the selection of reaction parameters such as temperature and concentration would have been obvious.

"Normally, it is to expected that a change in temperature, or in range, concentration, cycles, thickness, would be an unpatentable modification. Under some circumstance, however, changes such as these may be impart patentability to a process if the particular ranges claimed produce a new and unexpected result which is different in kind and not merely degree from the results of the prior art ... such ranges are termed "critical ranges and the applicant has the burden of proving such criticality ... More particularly, where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In re Aller 105 USPQ233, 255 (CCPA 1955). See also In re Waite 77 USPQ 586 (CCPA 1948); In re Scherl 70 USPQ 204 (CCPA 1946); In re Irmscher 66 USPQ 314 (CCPA 1945); In re Norman 66 USPQ 308 USPQ 308 (CCPA 1945); In re Swenson 56 USPQ 372 (CPA 1942); In re Sola 25 USPQ 433 (CCPA 1935); In re Dreyfus 24 USPQ 52 (CCPA 1934).

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## Response to Arguments

Applicant's arguments filed 2/3/03 have been fully considered but they are not persuasive.

Applicant's arguments is Summerfelt et al. don not disclose the perovskite type dielectric material having two layers against one another which both comprise barium, strontium, titanium and oxygen, and yet which differ in crystallinity relative to one another.

Summerfelt et al. do not disclose an crystallizing to the dielectric layers, but

Sone discloses the crystallizing to the dielectric layers by a two step deposition process.

Therefore, the dielectric layers is crystallized in two different thickness and formed on
two edge regions, one region is on the lower electrode and the other relative one is
further away from the first edge region, which adjacent to the top electrode and
extremely even (col.1& 2, lines 64-38), wherein the interface region between this is
unevenness (col.9, lines 16-24). The repeat crystalline dielectric film will change of
amount of crystalline structure when the crystallizing has grain structure and the
dielectric film are arranged in irregularly structure, thus crystalline amount is different in
the dielectric region (col.11, claim 11).

Sona also disclose the changes in crystallinity can influence and control leakage current, by forming a small roughness in one side of the dielectric film has and relative to one other side has evenness, which as a result of the leakage current and breakdown voltage are improved (col.4, lines 6-16).



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Sona also disclose the perovskite type dielectric material comprises Sr, Ba, Pb, Ti, Zr, and La (col. 5, lines 31-37).

#### Conclusion

This is a continuing of applicant's earlier Application No. 10/086942. All claims are drawn to the same invention claimed in the earlier application and could have been finally rejected on the grounds and art of record in the next Office action if they had been entered in the earlier application. Accordingly, **THIS ACTION IS MADE FINAL** even though it is a first action in this case. See MPEP § 706.07(b). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no, however, event will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Yennhu B. Huynh whose telephone number is 703-308-6110. The examiner can normally be reached on M-F 8.30AM-7.00PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead, can be reached 703-308-4940. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

YNBH,

2/13/03

CARL WHITEHEAD, JR. ERVISORY PATENT EXAMINED

TECHNOLOGY CENTER 2800